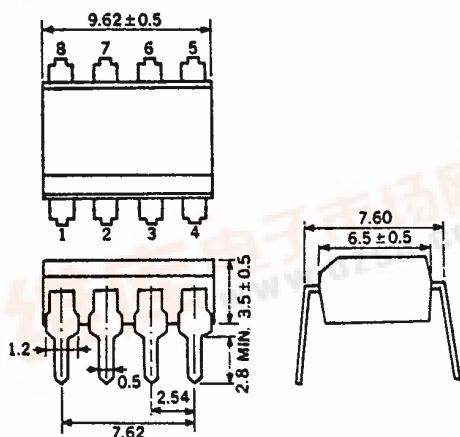


PHOTO COUPLER

PS2043

HIGH SPEED 8PIN PHOTO COUPLED

PACKAGE DIMENSIONS
(Unit: mm)

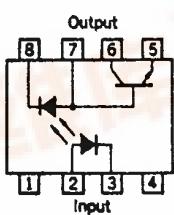
FEATURES

- High Speed Response 0.3 μ s TYP.
- High Isolation Voltage 2500 Vr.m.s.
- Compact, Dual In-Line Package

APPLICATIONS

1. Interface circuit for various instrumentations, control equipments.
2. Computer and peripheral manufactures.
3. TV sets.

PIN CONNECTION



PIN	Function
Input	1. NC
	2. Anode
	3. Cathode
	4. NC
Output	5. Emitter
	6. V _O
	7. Base
	8. V _{CC}

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Diode

Forward Current	I _F	25	mA
Reverse Voltage	V _R	5	V
Power Dissipation	P _D	45	mW
Detector			
Supply Voltage	V _{CC}	-0.5 to 15	V
Output Voltage	V _O	-0.5 to 15	V
Output Current	I _O	8	mA
Power Dissipation	P _C	100	mW
Isolation Voltage*	BV	2500	V _{r.m.s.}
Storage Temperature	T _{stg}	-55 to +125	°C
Operating Temperature	T _{opt}	-55 to +100	°C
Lead Temperature (10 s)		260	°C

* Condition

AC Voltage for 1 minute at $T_a = 25^\circ\text{C}$, RH = 60 % between input (pin No. 1, 2, 3, 4 Common) and output (pin No. 5, 6, 7, 8 Common)

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	V_F		1.7	2.2	V	$I_F = 16 \text{ mA}$
	Reverse Current	I_R		0.01	10	μA	$V_R = 5 \text{ V}$
	Forward Voltage Temperature Coefficient	$\frac{\Delta V_F}{\Delta T}$		-1.6		mV°C	$I_F = 16 \text{ mA}$
	Capacitance	C_F		60		pF	$V = 0, f = 1 \text{ MHz}$
Detector Coupled	High Level Output Current	$I_{OH} (1)$		3	500	nA	$I_F = 0 \text{ mA}, V_{CC} = V_O = 5.5 \text{ V}$
	High Level Output Current	$I_{OH} (2)$			100	μA	$I_F = 0 \text{ mA}, V_{CC} = V_O = 15 \text{ V}$
	Current Transfer Ratio	CTR *	15	22		%	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, V_O = 0.4 \text{ V}$
	Low Level Output Voltage	V_{OL}		0.1	0.4	V	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$
	Low Level Supply Current	I_{CCL}		50		μA	$I_F = 16 \text{ mA}, V_O = \text{Open}, V_{CC} = 15 \text{ V}$
	High Level Supply Current	I_{CH}		0.01	1	μA	$I_F = 0 \text{ mA}, V_O = \text{Open}, V_{CC} = 15 \text{ V}$
	Isolation Resistance	R_{1-2}	10^{11}			Ω	$V_{in-out} = 1 \text{ kV DC}$
	Isolation Capacitance	C_{1-2}		0.7		pF	$V = 0, f = 1 \text{ MHz}$
	Propagation Delay Time to Low Output Level	t_{PLH}^{**}		0.3	0.8	μs	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$
	Propagation Delay Time to High Output Level	t_{PHL}^{**}		$(K/L/R)$ 0.3/1.0/0.8	$(K/L/R)$ 0.8/1.5/1.25	μs	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$

* CTR rank

K: 15 % ~

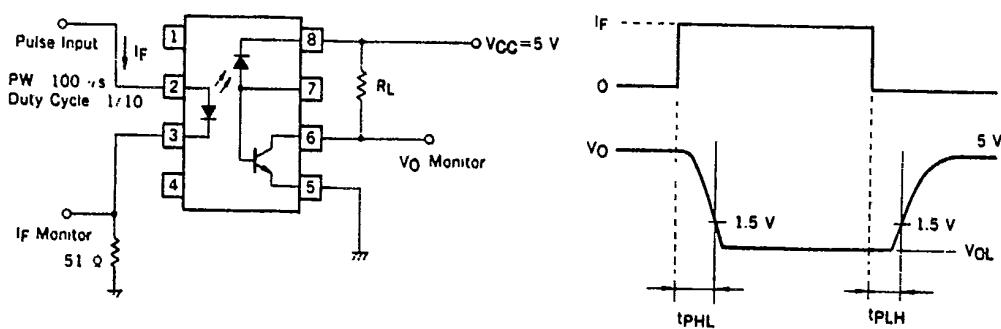
L: 25 % ~

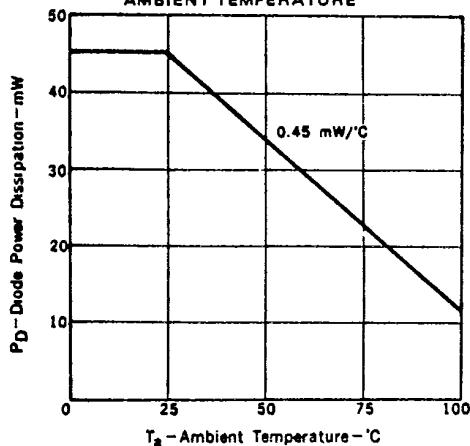
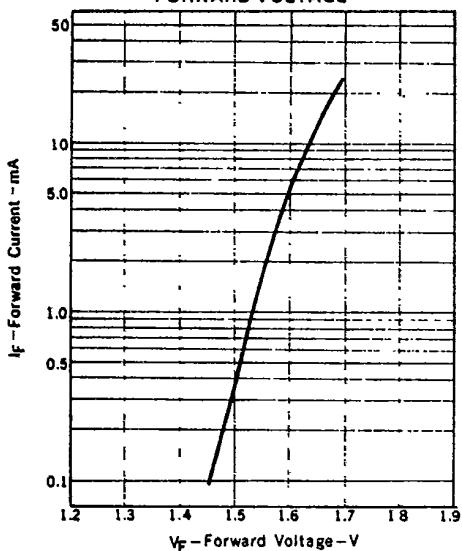
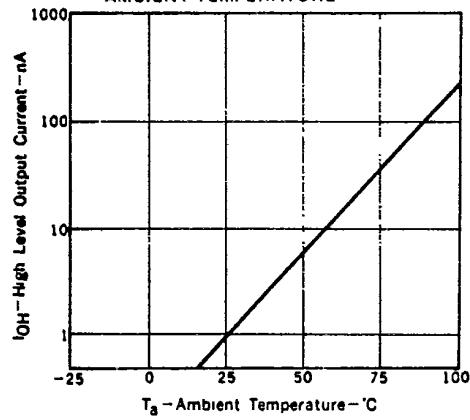
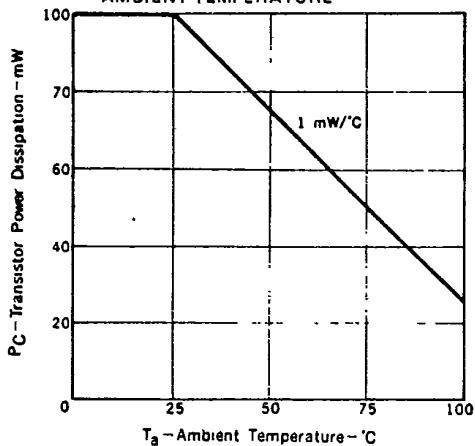
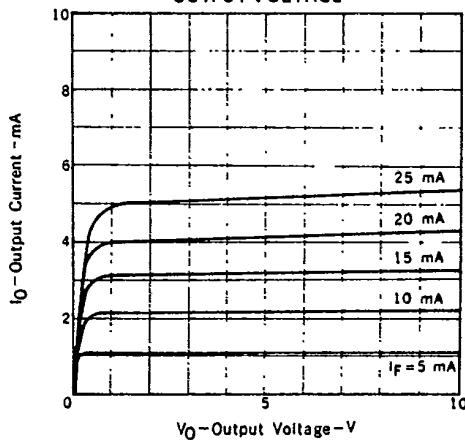
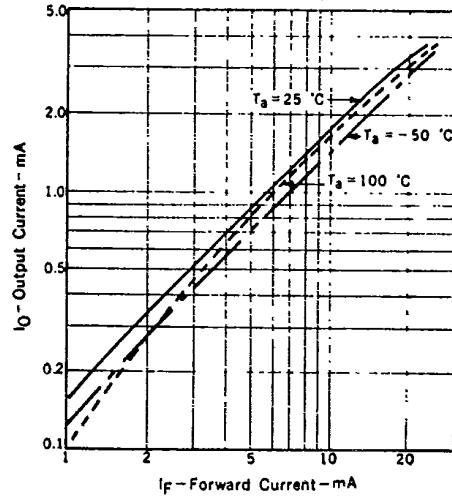
R: 20 % ~

** Measuring circuit

input PW = 100 μs

Duty = 10 %



TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)DIODE POWER DISSIPATION vs.
AMBIENT TEMPERATUREFORWARD CURRENT vs.
FORWARD VOLTAGEHIGH LEVEL OUTPUT CURRENT vs.
AMBIENT TEMPERATURETRANSISTOR POWER DISSIPATION vs.
AMBIENT TEMPERATUREOUTPUT CURRENT vs.
OUTPUT VOLTAGEOUTPUT CURRENT vs.
FORWARD CURRENT

PS2043

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